

HL6740FG Dual Beam Visible Laser Diode

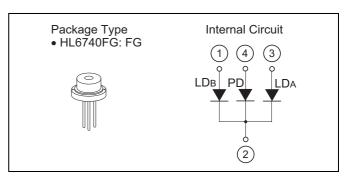
ODE-208-024 (Z) Rev.0 Feb. 24, 2006

Description

The HL6740FG is a 0.67 μ m band AlGaInP laser diode with a multi-quantum well (MQW) structure. It is an array of two individual beams on one chip. Therefore, it is suitable as a light source for a high-speed printer, such as PPC and LBP, and so on.

Features

- Continuous operating output to each beam: 5 mW CW
- Visible light output: 675 nm Typ
- Difference of wavelength between 2 beams : 3 nm Max
- Low threshold current: 35 mA Typ



Absolute Maximum Ratings

			$(T_{\rm C} = 25^{\circ}{\rm C})$	
ltem	Symbol	Ratings	Unit	
Optical output power	Po	5	mW	
Pulse optical output power	P _{O(pulse)}	6*	mW	
LD reverse voltage	V _{R(LD)}	2	V	
PD reverse voltage	V _{R(PD)}	30	V	
Operating temperature	Topr	-10 to +50	°C	
Storage temperature	Tstg	-40 to +85	°C	

Note: Pulse condition : Pulse width $\leq 1~\mu s,~duty \leq 50\%$

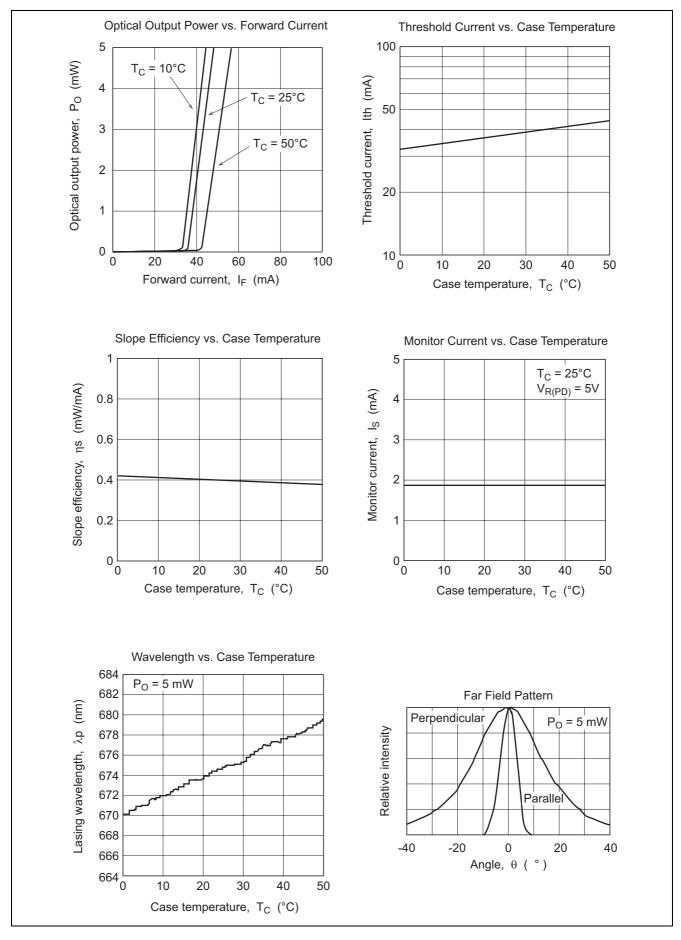
Optical and Electrical Characteristics

						$(T_{\rm C} = 25^{\circ}{\rm C})$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Threshold current	lth	—	35	50	mA	—
LD Operating current	I _{OP}	—	—	75	mA	$P_0 = 5 \text{ mW}$
LD Operating voltage	V _{OP}	—	2.3	2.7	V	$P_0 = 5 \text{ mW}$
Slope efficiency	ηs	0.2	0.4	0.6	mW/mA	$3 (mW) / (I_{(4mW)} - I_{(1mW)})$
Beam divergence parallel to the junction	θ//	6.5	8	11	0	P ₀ = 5 mW
Beam divergence perpendicular to the junction	θ⊥	20	30	36	o	P ₀ = 5 mW
Lasing wavelength	λр	665	675	680	nm	$P_0 = 5 \text{ mW}$
Difference of wavelength *2	Δλρ	—	—	3.0	nm	$P_0 = 5 \text{ mW}$
Monitor current	ls	1.0	_	4.0	mA	$P_0 = 5 \text{ mW}, V_{R(RD)} = 5V$

Notes: 1. The characteristics are specified under the condition of a single beam operation unless otherwise specified.
2. Δλp is specified as absolute value of the difference between two beams operated every beam.

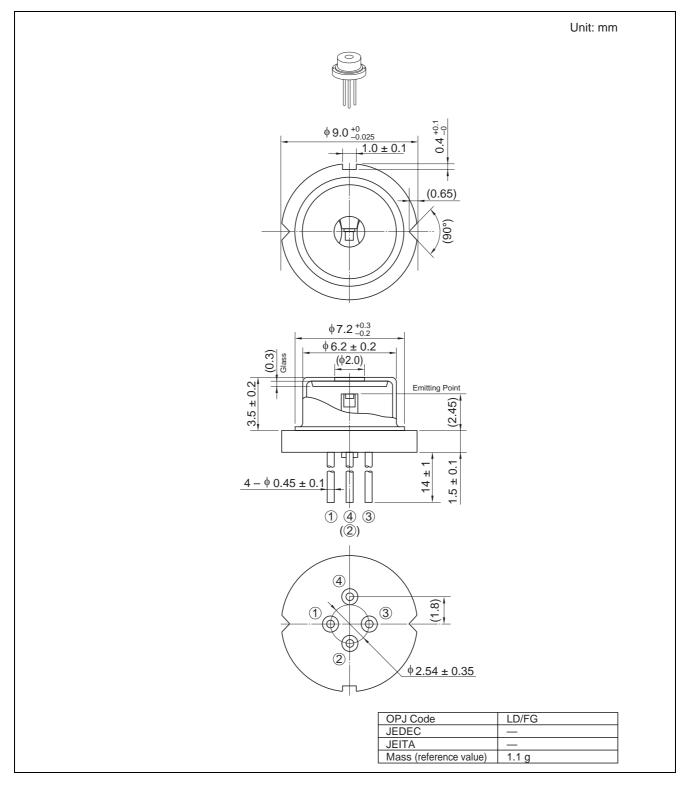


Typical Characteristic Curves





Package Dimensions





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- 1. The laser light is harmful to human body especially to eye no matter what directly or indirectly. The laser beam shall be observed or adjusted through infrared camera or equivalent.
- 2. This product contains gallium arsenide (GaAs), which may seriously endanger your health even at very low doses. Please avoid treatment which may create GaAs powder or gas, such as disassembly or performing chemical experiments, when you handle the product.

When disposing of the product, please follow the laws of your country and separate it from other waste such as industrial waste and household garbage.

3. Definition of items shown in this CAS is in accordance with that shown in Opto Device Databook issued by OPJ unless otherwise specified.

Sales Offices



Device Business Unit Opnext Japan, Inc.

Takagi Bldg., 3F, 1-3-9, Iwamoto-cho, Chiyoda-ku, Tokyo 101-0032 Japan Tel: (03) 3865-5591

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